

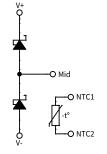
1700 V, 600 A, Silicon Carbide, Half-Bridge Rectifier

$V_{_{\rm R}}$	1700 V
I _F	600 A

Technical Features

- Ultra-Low Loss, High Frequency Operation
- Low Forward Voltage (V_F) Drop with Positive Temperature Coefficient
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Temperature-Independent Switching Behavior





Applications

- Railway, Traction, and Motor Drives
- EV Chargers
- High-Efficiency Converters / Inverters
- Renewable Energy
- Smart-Grid / Grid-Tied Distributed Generation

System Benefits

- Enables Compact, Lightweight Systems
- Increased System Efficiency, due to Low Switching & Conduction Losses of SiC
- Reduced Thermal Requirements and System Cost

Maximum Parameters (Verified by Design)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions	Note
Maximum Reverse Voltage	V_{R-Max}			1700	V		
Continuous Formund Communt	I _F		986			T _c = 25°C, T _W ≤ 175°C	
Continuous Forward Current			702			T _C = 90°C, T _{VJ} ≤ 175°C	
Maximum Pulsed Forward Current	I _{F (Pulsed)}			1200	A	t_{Pmax} limited by T_{VJmvax} $T_C = 25$ °C	
Maximum Virtual Junction Temperature	T _{vJ}	-40		175	°C		

Diode Characteristics (Per Position) ($T_{VJ} = 25$ °C unless otherwise specified)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions	Note
Diada Farruard Valtarra	V		1.6		V	I _F = 600 A	
Diode Forward Voltage	V _F		2.2			I _F = 600 A, T _{VJ} = 175°C	
Reverse Current			0.06		А	V _R = 1700 V, T _{VJ} = 25°C	
	I _R		0.29		mA	V _R = 1700 V, T _{VJ} = 175°C	
Total Capacitive Charge	Qc		4.9		mC	V _R = 1100 V	
			55.7		nF	V _R = 0 V, f = 100 kHz	
Total Capacitance	С		2.9			V _R = 550 V, f = 100 kHz	
			2.7			V _R = 1100 V, f = 100 kHz	
Thermal Resistance, Junction to Case	R _{TH-JC}		0.048			Per position	

Note:

 $^{^{1}}$ SiC Schottky diodes are majority carrier devices, so there is no reverse recovery charge.

Module Physical Characteristics

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Package Resistance, M1 (High-Side)	R ₁₋₂		106.5		0	T _c = 125°C, Note 1
Package Resistance, M2 (Low-Side)	R ₂₋₃		126.3		μΩ	T _c = 125°C, Note 1
Stray Inductance	L_{Stray}		4.9		nH	Between DC- and DC+, f = 10 MHz
Case Temperature	T _c	-40		125	°C	
		3	4.5	5	N-m	Baseplate, M6 bolts
Mounting Torque	Ms	0.9	1.1	1.3		Power Terminals, M4 bolts
Weight	W		167		g	
Case Isolation Voltage	V _{isol}	4			kV	AC, 50 Hz, 1 minute
Comparative Tracking Index	СТІ	600				
Clearance Distance		13.07				Terminal to Terminal
		6.00				Terminal to Heatsink
		14.27			mm	Terminal to Terminal
Creepage Distance		12.34				Terminal to Heatsink

NTC Characteristics (T_{NTC} = 25 °C unless otherwise specified)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Notes
Resistance at 25°C	R ₂₅		4700		Ω	
Tolerance of R ₂₅			±1		%	
Beta Value for 25°C to 85°C	B _{25/85}		3435		K	
Beta Value for 0°C to 100°C	B _{0/100}		3399		K	
Tolerance of B _{25/85}			±1		%	
Maximum Power Dissipation	P _{Max}		50		mW	

Steinhart & Hart Coefficients for NTC Resistance & NTC Temperature Computation (T in K)

$$\ln\left(\frac{R}{R_{25}}\right) = A + \frac{B}{T} + \frac{C}{T^2} + \frac{D}{T^3}$$

$$\ln\left(\frac{R}{R_{25}}\right) = A + \frac{B}{T} + \frac{C}{T^2} + \frac{D}{T^3}$$

$$\frac{1}{T} = A_1 + B_1 \ln\left(\frac{R}{R_{25}}\right) + C_1 \ln^2\left(\frac{R}{R_{25}}\right) + D_1 \ln^3\left(\frac{R}{R_{25}}\right)$$

A_{1}	B_1	C_1	D_1
3.354E-03	3.001E-04	5.085E-06	2.188E-07

Typical Performance

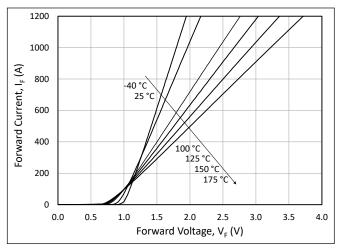


Figure 1. Typical Forward Characteristics

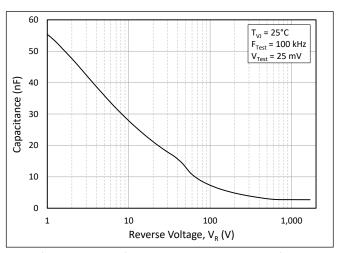


Figure 3. Typical Capacitance vs. Reverse Voltage

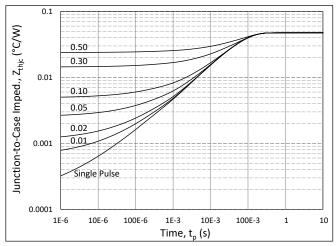


Figure 5. Diode Junction to Case Transient Thermal Impedance, $Z_{th,JC}$ (°C/W)

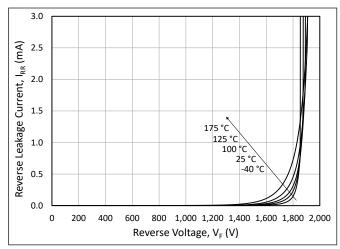


Figure 2. Typical Reverse Characteristics

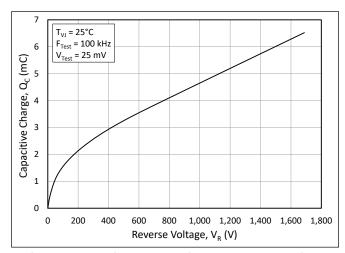


Figure 4. Typical Capacitive Charge vs. Reverse Voltage

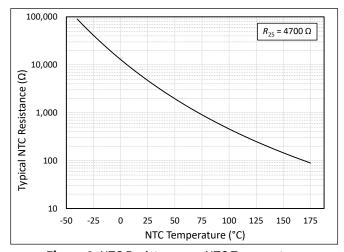
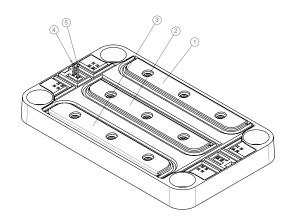
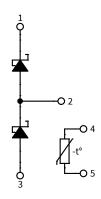


Figure 6. NTC Resistance vs. NTC Temperature

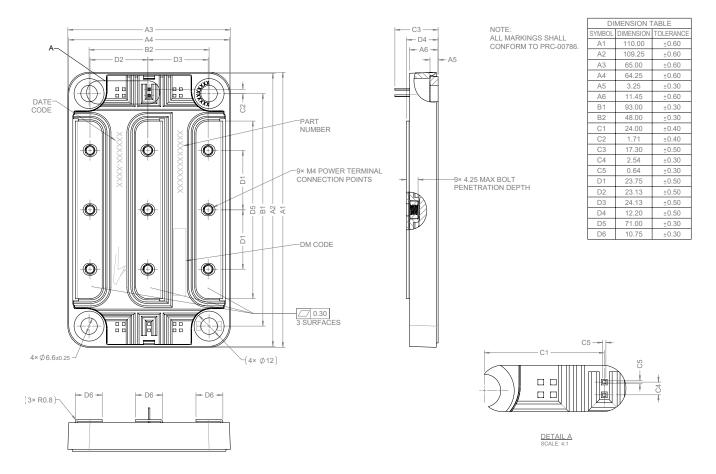
Schematic and Pin Out



PIN OUT SCHEME				
PIN	LABEL			
1	V+			
2	Mid			
3	V-			
4	NTC1			
(5)	NTC2			



Package Dimension (mm)



Supporting Links & Tools

Evaluation Tools & Support

- CAR600M17HN6 PLECS Model
- SpeedFit 2.0 Design Simulator™
- Technical Support Forum

Application Notes

- CPWR-AN35: 62mm Thermal Interface Material Application Note
- CPWR-AN39: KIT-CRD-CIL12N-HM User Guide

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